

# DATA SHEET

## **74LV174**

Hex D-type flip-flop with reset;  
positive-edge trigger

Product specification  
Supersedes data of 1997 Apr 07  
IC24 Data Handbook

1998 May 20

## Hex D-type flip-flop with reset; positive edge-trigger

74LV174

## FEATURES

- Wide operating voltage: 1.0 to 5.5V
- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between  $V_{CC} = 2.7V$  and  $V_{CC} = 3.6V$
- Typical  $V_{OLP}$  (output ground bounce)  $< 0.8V$  @  $V_{CC} = 3.3V$ ,  $T_{amb} = 25^{\circ}C$
- Typical  $V_{OHV}$  (output  $V_{OH}$  undershoot)  $> 2V$  @  $V_{CC} = 3.3V$ ,  $T_{amb} = 25^{\circ}C$
- Output capability: standard
- $I_{CC}$  category: MSI

## DESCRIPTION

The 74LV174 is a low-voltage Si-gate CMOS device and is pin and function compatible with the 74HC/HCT174.

The 74LV174 has six edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common clock (CP) and master reset (MR) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one set-up time prior to the LOW-to-HIGH clock transition, is transferred to the corresponding output of the flip-flop.

A LOW level on the MR input forces all outputs LOW, independently of clock or data inputs.

The device is useful for applications requiring true outputs only and clock and master reset inputs that are common to all storage elements.

## QUICK REFERENCE DATA

GND = 0V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \leq 2.5$  ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
$t_{PHL}/t_{PLH}$	Propagation delay CP to $Q_n$ MR to $Q_n$	$C_L = 15pF$ $V_{CC} = 3.3V$	16 13	ns
$f_{max}$	Maximum clock frequency		77	
$C_i$	Input capacitance		3.5	pF
$C_{PD}$	Power dissipation capacitance per flip-flop	$V_{CC} = 3.3V$ Notes 1 and 2	17	pF

## NOTES:

- $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ )  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz;  $C_L$  = output load capacitance in pF;  
 $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;  
 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.
- The condition is  $V_i = GND$  to  $V_{CC}$

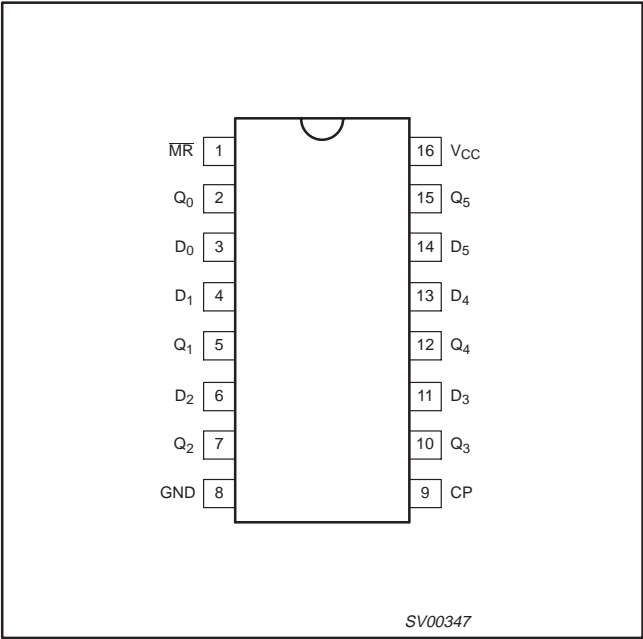
## ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	$-40^{\circ}C$ to $+125^{\circ}C$	74LV174 N	74LV174 N	SOT38-4
16-Pin Plastic SO	$-40^{\circ}C$ to $+125^{\circ}C$	74LV174 D	74LV174 D	SOT109-1
16-Pin Plastic SSOP Type II	$-40^{\circ}C$ to $+125^{\circ}C$	74LV174 DB	74LV174 DB	SOT338-1
16-Pin Plastic TSSOP	$-40^{\circ}C$ to $+125^{\circ}C$	74LV174 PW	74LV174PW DH	SOT403-1

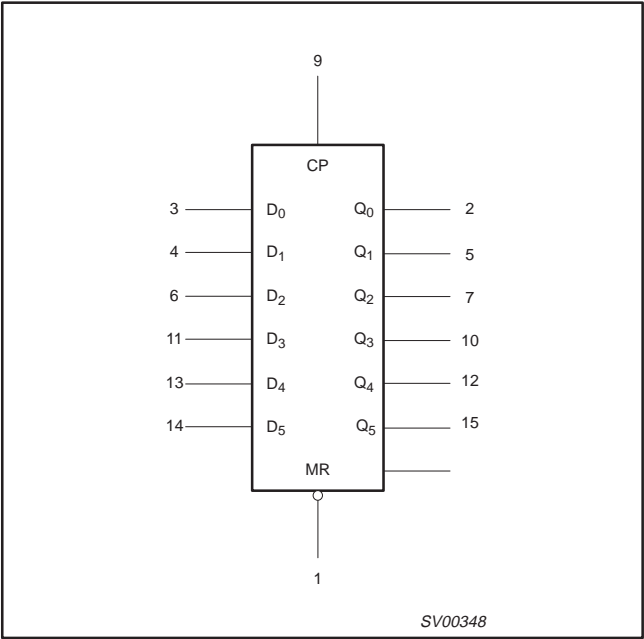
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PIN CONFIGURATION



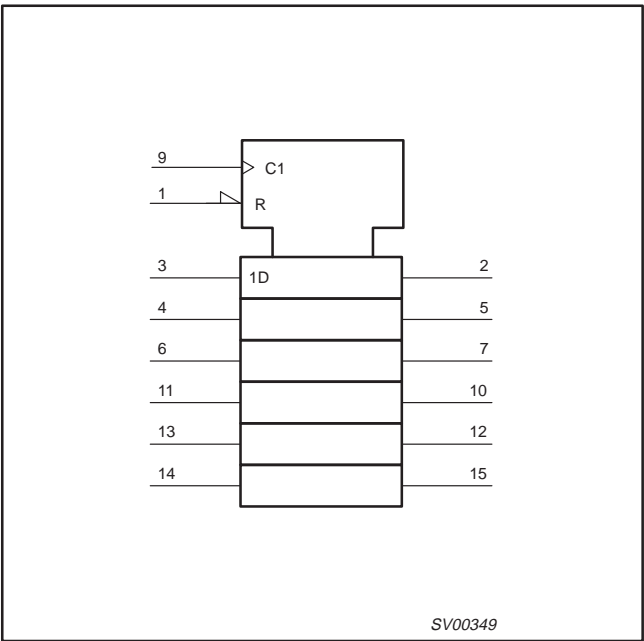
LOGIC SYMBOL



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	$\overline{MR}$	Asynchronous master reset (active LOW)
2, 5, 7, 10, 12, 15	$Q_0$ to $Q_5$	Flip-flop outputs
3, 4, 6, 11, 13, 14	$D_0$ to $D_5$	Data inputs
8	GND	Ground (0V)
9	CP	Clock input (LOW-to-HIGH, edge-triggered)
16	$V_{CC}$	Positive supply voltage

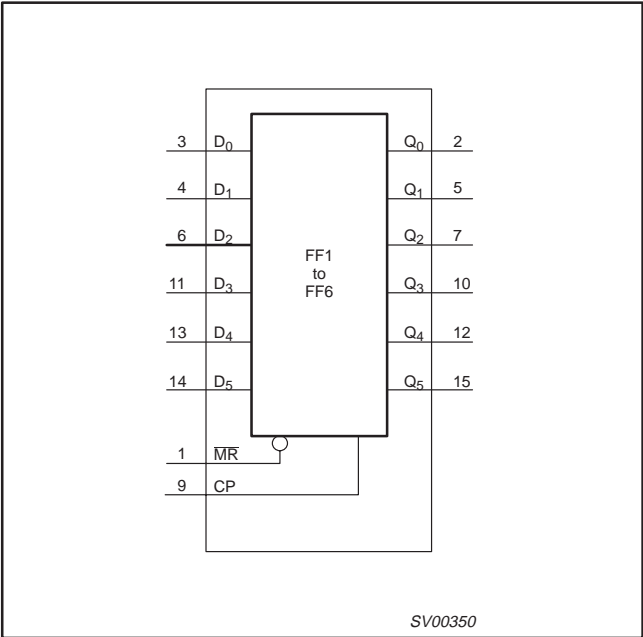
LOGIC SYMBOL (IEEE/IEC)



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FUNCTIONAL DIAGRAM



FUNCTION TABLE

OPERATING MODES	INPUTS			OUTPUTS
	MR	CP	D <sub>n</sub>	Q <sub>0</sub>
Reset (clear)	L	X	X	L
Load '1'	H	↑	h	H
Load '0'	H	↑	l	L

- H = HIGH voltage level  
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition  
L = LOW voltage level  
l = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition  
q = Lower case letter indicates the state of referenced input one set-up time prior to the LOW-to-HIGH CP transition  
↑ = LOW-to-HIGH clock transition

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note1	1.0	3.3	5.5	V
V <sub>I</sub>	Input voltage		0	–	V <sub>CC</sub>	V
V <sub>O</sub>	Output voltage		0	–	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	–40 –40		+85 +125	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	V <sub>CC</sub> = 1.0V to 2.0V V <sub>CC</sub> = 2.0V to 2.7V V <sub>CC</sub> = 2.7V to 3.6V V <sub>CC</sub> = 3.6V to 5.5V	– – – –	– – – –	500 200 100 50	ns/V

NOTES:

1. The LV is guaranteed to function down to V<sub>CC</sub> = 1.0V (input levels GND or V<sub>CC</sub>); DC characteristics are guaranteed from V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 5.5V.

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**ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
$V_{CC}$	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_I < -0.5$ or $V_I > V_{CC} + 0.5V$	20	mA
$\pm I_{OK}$	DC output diode current	$V_O < -0.5$ or $V_O > V_{CC} + 0.5V$	50	mA
$\pm I_O$	DC output source or sink current – standard outputs	$-0.5V < V_O < V_{CC} + 0.5V$	25	mA
$\pm I_{GND},$ $\pm I_{CC}$	DC $V_{CC}$ or GND current for types with –standard outputs		50	mA
$T_{stg}$	Storage temperature range		-65 to +150	°C
$P_{TOT}$	Power dissipation per package –plastic DIL –plastic mini-pack (SO) –plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

**NOTES:**

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

**DC CHARACTERISTICS FOR THE LV FAMILY**

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40°C to +85°C			-40°C to +125°C		
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
V <sub>IH</sub>	HIGH level Input voltage	V <sub>CC</sub> = 1.2V	0.9			0.9		V
		V <sub>CC</sub> = 2.0V	1.4			1.4		
		V <sub>CC</sub> = 2.7 to 3.6V	2.0			2.0		
		V <sub>CC</sub> = 4.5 to 5.5V	0.7*V <sub>CC</sub>			0.7*V <sub>CC</sub>		
V <sub>IL</sub>	LOW level Input voltage	V <sub>CC</sub> = 1.2V			0.3		0.3	V
		V <sub>CC</sub> = 2.0V			0.6		0.6	
		V <sub>CC</sub> = 2.7 to 3.6V			0.8		0.8	
		V <sub>CC</sub> = 4.5 to 5.5			0.3*V <sub>CC</sub>		0.3*V <sub>CC</sub>	
V <sub>OH</sub>	HIGH level output voltage; all outputs	V <sub>CC</sub> = 1.2V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 100μA		1.2				V
		V <sub>CC</sub> = 2.0V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 100μA	1.8	2.0		1.8		
		V <sub>CC</sub> = 2.7V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 100μA	2.5	2.7		2.5		
		V <sub>CC</sub> = 3.0V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 100μA	2.8	3.0		2.8		
		V <sub>CC</sub> = 4.5V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 100μA	4.3	4.5		4.3		
	HIGH level output voltage; STANDARD outputs	V <sub>CC</sub> = 3.0V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 6mA	2.40	2.82		2.20		V
		V <sub>CC</sub> = 4.5V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; -I <sub>O</sub> = 12mA	3.60	4.20		3.50		
	V <sub>OL</sub>	LOW level output voltage; all outputs	V <sub>CC</sub> = 1.2V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 100μA		0			
V <sub>CC</sub> = 2.0V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 100μA				0	0.2		0.2	
V <sub>CC</sub> = 2.7V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 100μA				0	0.2		0.2	
V <sub>CC</sub> = 3.0V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 100μA				0	0.2		0.2	
V <sub>CC</sub> = 4.5V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 100μA				0	0.2		0.2	
LOW level output voltage; STANDARD outputs		V <sub>CC</sub> = 3.0V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 6mA		0.25	0.40		0.50	V
		V <sub>CC</sub> = 4.5V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; I <sub>O</sub> = 12mA		0.35	0.55		0.65	

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**DC CHARACTERISTICS FOR THE LV FAMILY (Continued)**

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40°C to +85°C			-40°C to +125°C		
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> = 5.5V; V <sub>I</sub> = V <sub>CC</sub> or GND			1.0		1.0	μA
I <sub>CC</sub>	Quiescent supply current; MSI	V <sub>CC</sub> = 5.5V; V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0			20.0		160	μA
ΔI <sub>CC</sub>	Additional quiescent supply current per input	V <sub>CC</sub> = 2.7V to 3.6V; V <sub>I</sub> = V <sub>CC</sub> -0.6V			500		850	μA

**NOTE:**1. All typical values are measured at  $T_{amb} = 25^\circ C$ .**AC CHARACTERISTICS**GND = 0V;  $t_r = t_f = 2.5ns$ ;  $C_L = 50pF$ ;  $R_L = 1K\Omega$ 

SYMBOL	PARAMETER	WAVEFORM	CONDITION	LIMITS -40 to +85 °C			LIMITS -40 to +125 °C		UNIT
				MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
$t_{PHL}/t_{PLH}$	Propagation delay CP to $Q_n$	Figure 1	$V_{CC}(V)$						ns
			1.2	—	100	—	—	—	
			2.0	—	34	43	—	53	
			2.7	—	25	31	—	39	
			3.0 to 3.6	—	19 <sup>2</sup>	25	—	31	
$t_{PHL}$	Propagation delay MR to $Q_n$	Figure 2	4.5 to 5.5	—	13 <sup>3</sup>	21	—	26	ns
			1.2	—	80	—	—	—	
			2.0	—	27	43	—	53	
			2.7	—	20	31	—	39	
			3.0 to 3.6	—	15 <sup>2</sup>	25	—	31	
$t_W$	Clock pulse width HIGH to LOW	Figure 1	4.5 to 5.5	—	11 <sup>3</sup>	21	—	26	ns
			2.0	34	10	—	41	—	
			2.7	25	8	—	30	—	
			3.0 to 3.6	20	6 <sup>2</sup>	—	24	—	
$t_W$	Master reset pulse width LOW	Figure 2	4.5 to 5.5	13	4 <sup>3</sup>	—	16	—	ns
			2.0	34	9	—	41	—	
			2.7	25	6	—	30	—	
			3.0 to 3.6	20	5	—	24	—	
$t_{rem}$	Removal time MR to CP	Figure 2	4.5 to 5.5	13	4 <sup>2</sup>	—	16	—	ns
			1.2	—	-20	—	—	—	
			2.0	5	-7	—	5	—	
			2.7	5	-5	—	5	—	
			3.0 to 3.6	5	-4 <sup>2</sup>	—	5	—	
$t_{su}$	Set-up time $D_n$ to CP	Figure 3	4.5 to 5.5	5	-3 <sup>3</sup>	—	5	—	ns
			1.2	—	10	—	—	—	
			2.0	22	4	—	26	—	
			2.7	16	3	—	19	—	
			3.0 to 3.6	13	2 <sup>2</sup>	—	15	—	

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AC CHARACTERISTICS (Continued)

GND = 0V;  $t_r = t_f = 2.5\text{ns}$ ;  $C_L = 50\text{pF}$ ;  $R_L = 1\text{K}\Omega$

SYMBOL	PARAMETER	WAVEFORM	CONDITION	LIMITS −40 to +85 °C			LIMITS −40 to +125 °C		UNIT
			$V_{CC}(\text{V})$	MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
$t_h$	Hold time $D_n$ to CP	Figure 3	1.2	–	–10	–	–	–	ns
			2.0	5	–4	–	5	–	
			2.7	5	–2	–	5	–	
			3.0 to 3.6	5	–2 <sup>2</sup>	–	5	–	
			4.5 to 5.5	5	–1 <sup>3</sup>	–	5	–	
$f_{\text{max}}$	Maximum clock pulse frequency	Figure 1	2.0	14	40	–	12	–	MHz
			2.7	19	58	–	16	–	
			3.0 to 3.6	24	70 <sup>2</sup>	–	20	–	
			4.5 to 5.5	36	100 <sup>3</sup>	–	30	–	

NOTES:

1. Unless otherwise stated, all typical values are at  $T_{\text{amb}} = 25^\circ\text{C}$ .
2. Typical value measured at  $V_{CC} = 3.3\text{V}$ .
3. Typical value measured at  $V_{CC} = 5.0\text{V}$ .

AC WAVEFORMS

$V_M = 1.5\text{V}$  at  $V_{CC} \geq 2.7\text{V} \leq 3.6\text{V}$

$V_M = 0.5V \cdot V_{CC}$  at  $V_{CC} < 2.7\text{V}$  and  $\geq 4.5\text{V}$

$V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.

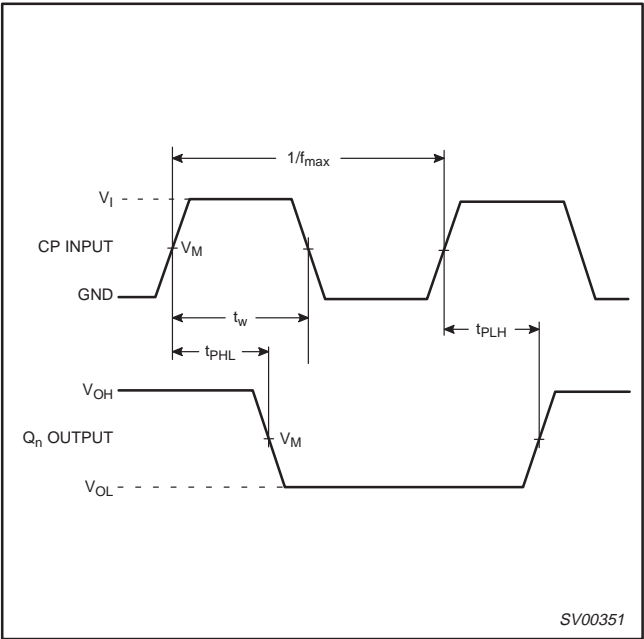


Figure 1. The clock (CP) to output ( $Q_n$ ) propagation delays, the clock pulse width, and the maximum clock pulse frequency.

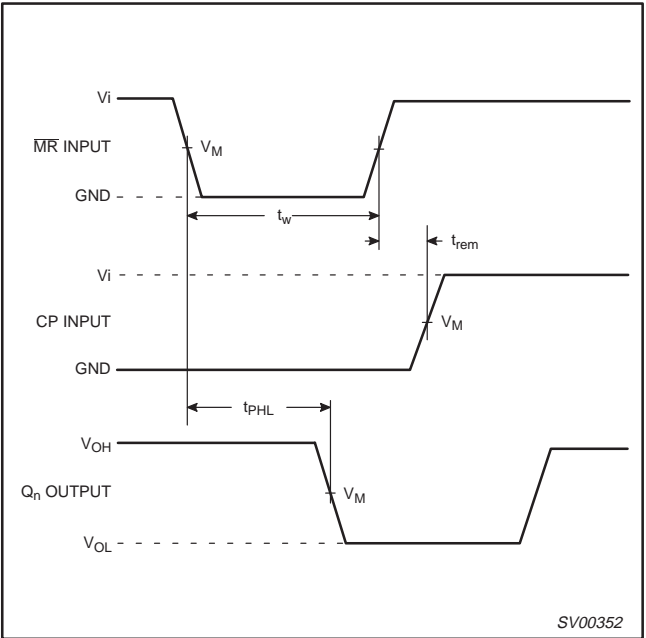


Figure 2. The master reset ( $\overline{\text{MR}}$ ) pulse width, the master reset to output ( $Q_n$ ) propagation delay and the master reset to clock removal time.

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AC WAVEFORMS (Continued)

$V_M = 1.5V$  at  $V_{CC} \geq 2.7V \leq 3.6V$   
 $V_M = 0.5V * V_{CC}$  at  $V_{CC} < 2.7V$  and  $\geq 4.5V$   
 $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.

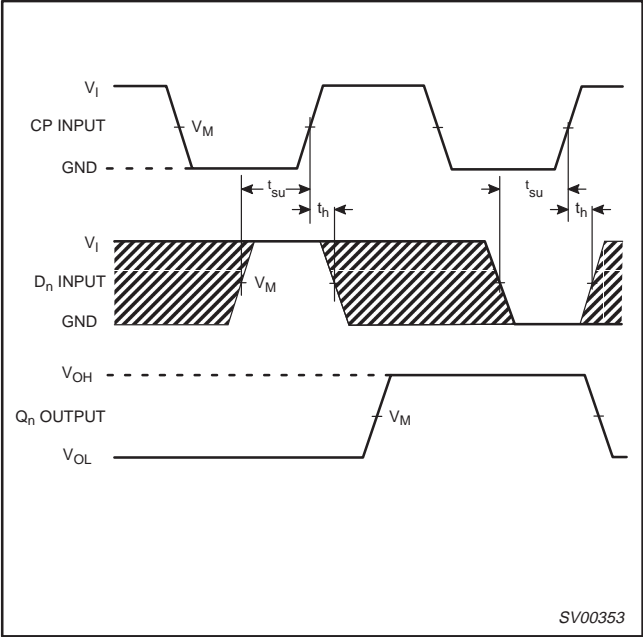


Figure 3. Data set-up and hold times for the data input (D<sub>n</sub>).

**NOTE:**  
The shaded areas indicate when the input is permitted to change for predictable output performance.

TEST CIRCUIT

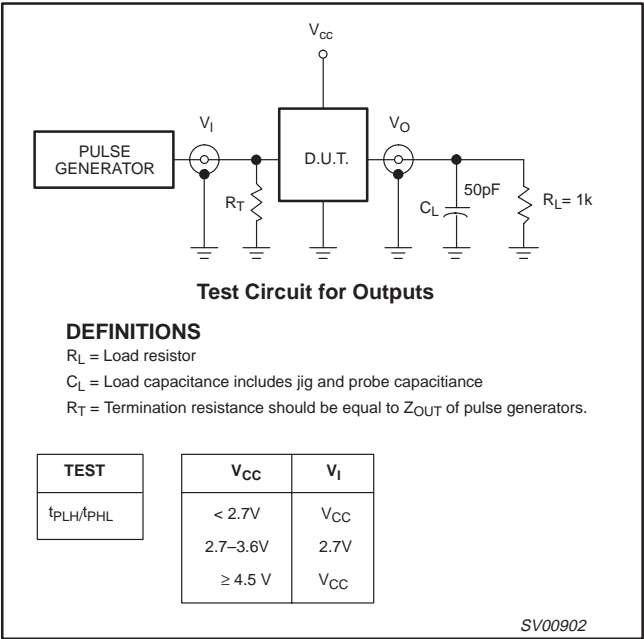


Figure 4. Load circuitry for switching times

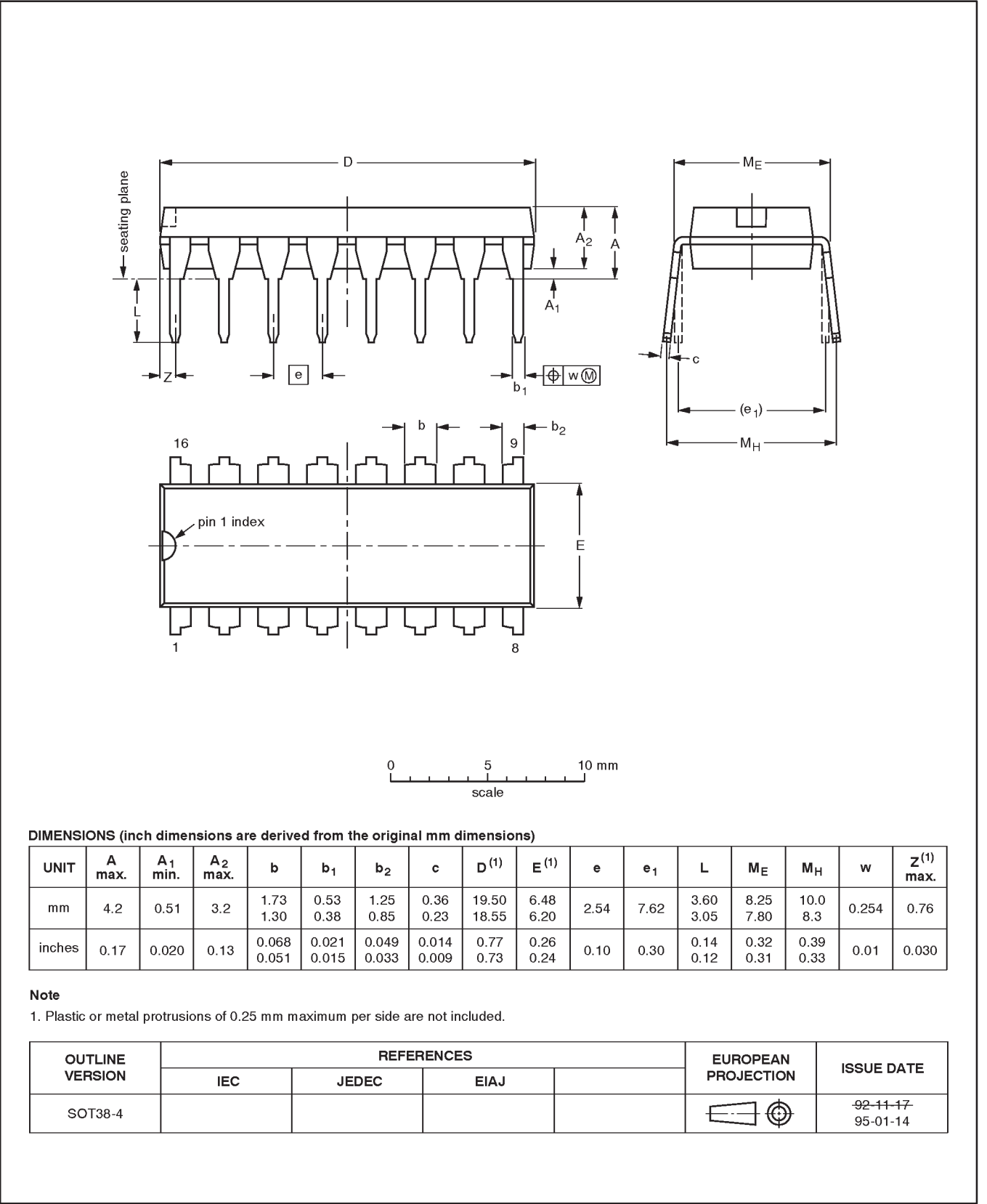


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DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

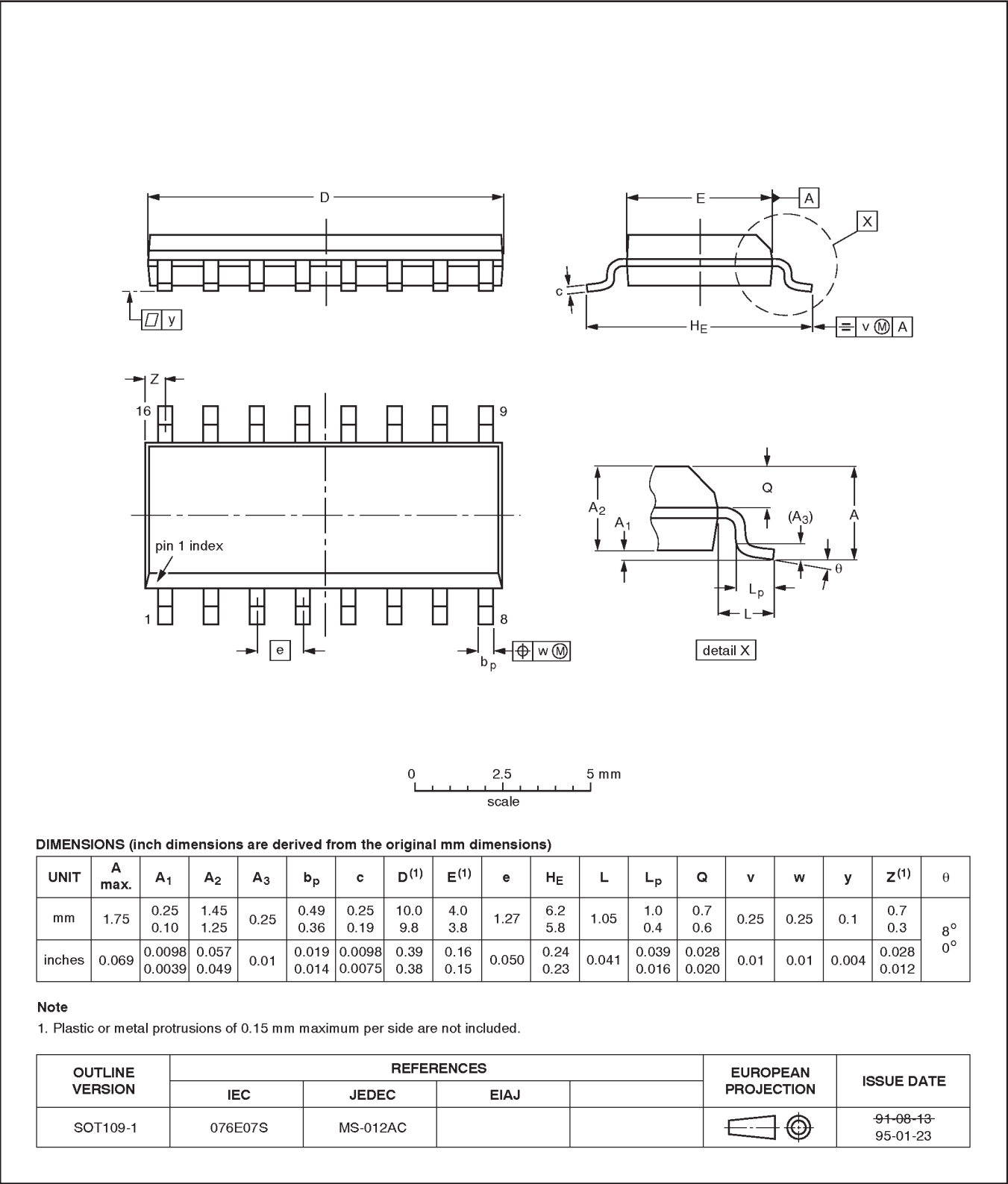


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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

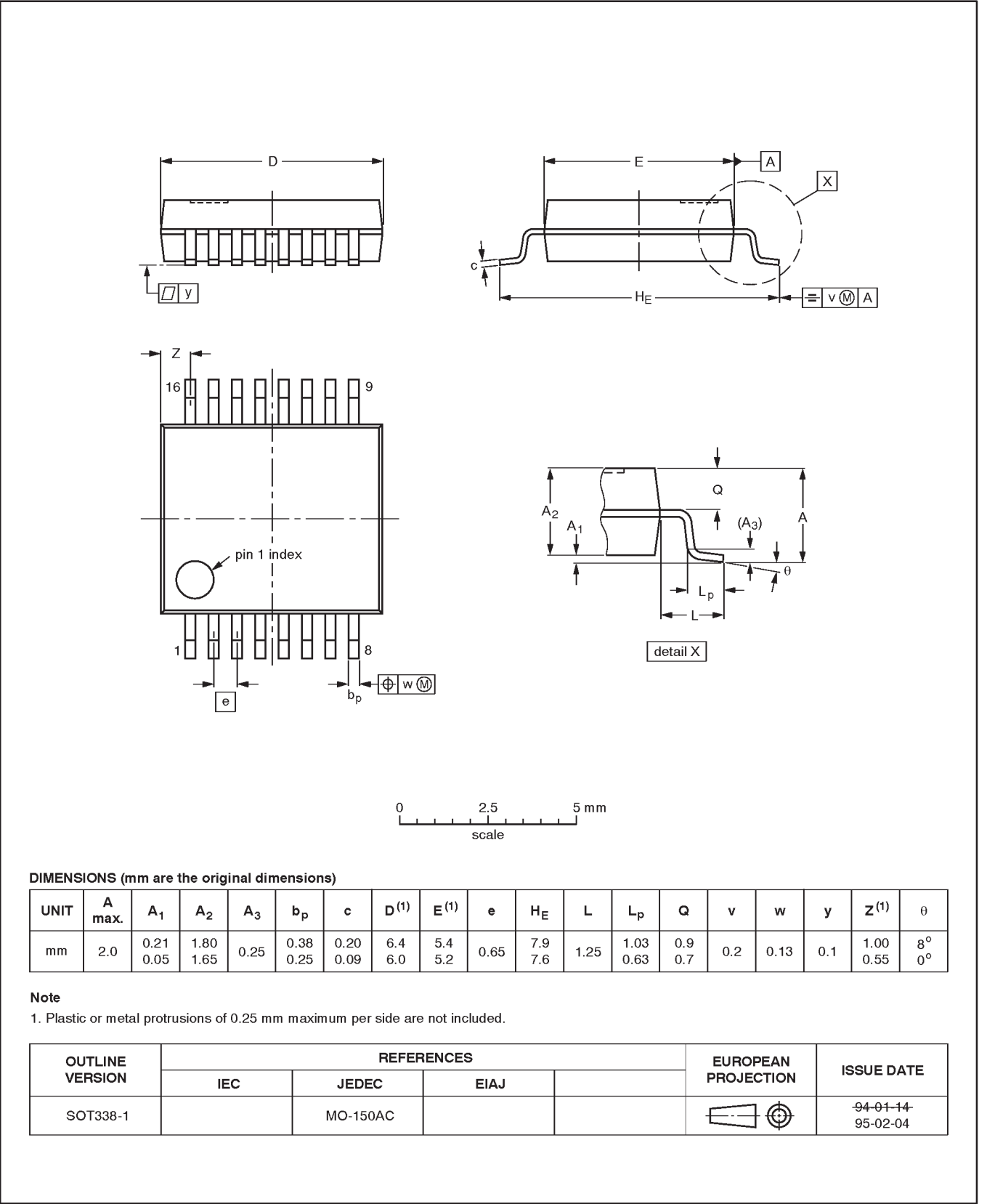


Hex D-type flip-flop with reset; positive edge-trigger

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

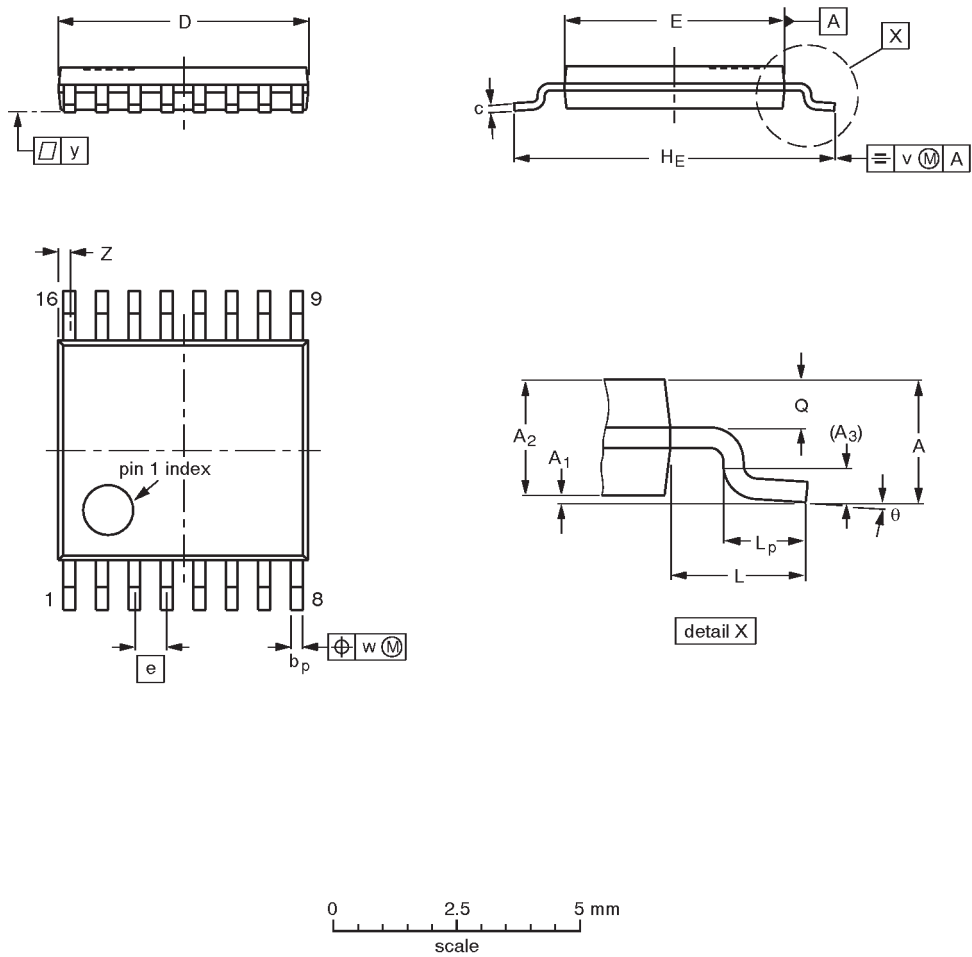


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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



DIMENSIONS (mm are the original dimensions)

UNIT	A <sub>max.</sub>	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(2)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT403-1		MO-153				94-07-12 95-04-04

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**NOTES**

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## DEFINITIONS

Data Sheet Identification	Product Status	Definition
<i>Objective Specification</i>	<b>Formative or in Design</b>	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
<i>Preliminary Specification</i>	<b>Preproduction Product</b>	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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